# Digital Delay/Pulse Generator

DG645 — Digital delay and pulse generator (4 or 8 channels)



- · 4 pulse, 8 delay outputs (opt.)
- · <25 ps rms jitter
- · Trigger rates to 10 MHz
- · Precision rate generator
- Fast transition times
- Ovenized crystal or Rb timebase (opt.)
- · Ethernet, GPIB and RS-232 interfaces

## **DG645 Digital Delay/Pulse Generator**

The DG645 is a versatile digital delay/pulse generator that provides precisely defined pulses at repetition rates up to 10 MHz. The instrument offers several improvements over older designs — lower jitter, higher accuracy, faster trigger rates, and more outputs. The DG645 also has Ethernet, GPIB and RS-232 interfaces for computer or network control of the instrument.

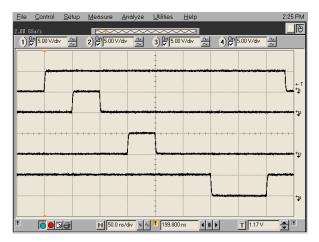
### **Delay Generator Timing**

All digital delay generators measure time intervals by counting cycles of a fast clock (typically 100 MHz). Most digital delay generators also have short programmable analog delays to achieve time intervals with finer resolution than the clock period. Unfortunately, one clock cycle of timing indeterminacy (typically 10 ns) can occur if the trigger is not in phase with the clock.

The DG645 eliminates timing indeterminacy by measuring the timing of triggers with respect to the internal clock and compensating the analog delays. This approach reduces the jitter by about 100× and allows the internal rate generator to operate at any rate — not just a sub-multiple of the clock frequency.

#### **Triggering**

The DG645 has many trigger modes. An internal rate generator, with less than 100 ps period jitter, may be set from



Front-panel outputs (50 ns/div)

 $100\,\mu\text{Hz}$  to 10 MHz with  $1\,\mu\text{Hz}$  resolution. An external trigger input, with adjustable threshold and slope, can trigger a timing cycle, a burst of cycles, or a single shot. A single shot can be triggered with a key press. A line trigger operates synchronously with the AC mains. A rear-panel trigger inhibit input can disable the trigger or any of the pulse outputs during a timing cycle.

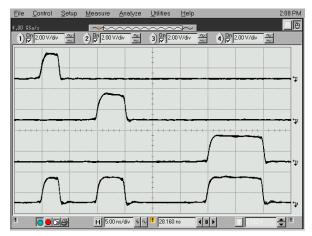
#### **Front-Panel Outputs**

There are five front-panel outputs:  $T_0$ , AB, CD, EF and GH. The  $T_0$  output is asserted for the duration of the timing cycle. The leading edge of  $T_0$  is the zero time reference. The programmed delays (A, B, C, D, E, F, G and H) are set from 0 s to 2000 s, with 5 ps resolution, to control the timing of the leading and trailing edges of the four pulse outputs.

Each front-panel output can drive a 50  $\Omega$  load and has a 50  $\Omega$  source impedance. Output amplitudes can be set from 0.5 to 5.0 V, and output offsets can range over ±2 VDC to source virtually any logic level (NIM, ECL, PECL, CMOS, etc.). Output transition times are less than 2 ns at any output amplitude.

#### **Rear-Panel Outputs**

Optional rear-panel outputs are available to support diverse applications. Option 1 provides a  $T_0$  output and eight programmed delays (A, B, C, D, E, F, G and H) at 5 V logic levels, with transition times less than 1 ns. Option 2 provides these same outputs but as 30 V, 100 ns pulses with less than 5 ns transition times for timing distribution in high noise environments. Option 3 provides eight combinatorial outputs which deliver one to four pulses at 5 V logic levels with less than 1 ns transition times. Each output has a 50  $\Omega$  source impedance.

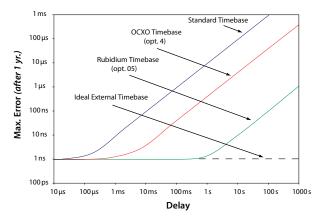


Combinatorial outputs showing 3 ns, 5 ns and 10 ns pulses with 1 ns transition times (5 ns/div)

#### **Timebases**

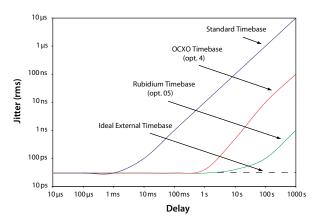
The standard time base has an accuracy of 5 ppm, and a jitter of 10<sup>-8</sup>, which is suitable for many applications. Optional timebases are available for users who require better rate and delay accuracy or reduced rate and delay jitter.

The timing error for a 1 s delay can be as large as 5 µs for the standard timebase, 200 ns for the OCXO timebase, but is only 500 ps for the rubidium timebase (all 1 year after calibration.)



Timing error vs. programmed delay

For short delays the jitter is typically 20 ps. However, for a 1 s delay, the standard timebase can contribute up to 10 ns of jitter, while the optional timebases contribute less than 10 ps of additional jitter.



Jitter vs. programmed delay

#### **Fast Rise Time Module**

The DG645 front-panel outputs have transition times of less than 2 ns. The SRD1 is an accessory, built into an in-line BNC connector, which reduces the rise time of a front-panel output to less than 100 ps. Up to 5 SRD1s can be attached to the front panel to reduce the rise time of all of the outputs.



SRD1 Fast Rise Time Module



DG645 (cover removed) with optional Rb timebase. Rear panel shows the optional eight-channel outputs.

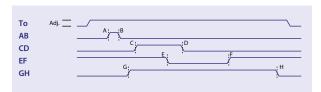
## **Ordering Information**

DG645 Delay/pulse generator Option 01 Eight delay channels (5 V) Option 02 Eight delay channels (30 V) Option 03 Combinatorial outputs Option 04 OCXO timebase Option 05 Rubidium timebase SRD1 100 ps rise time module O645RMS Single rack mount kit O645RMD Dual rack mount kit

## **More About the Outputs**

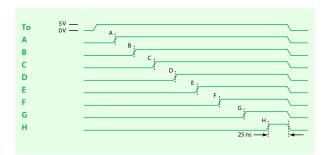
A timing cycle is initiated by an internal or external trigger. The  $T_0$  output, whose leading edge is the zero-time reference, is asserted 85 ns after the trigger. The delay settings (A, B, C, D, E, F, G and H) determine the timing of the front-panel and rear-panel outputs.

The front-panel outputs have adjustable amplitude, offset, and polarity (non-inverted or inverted).



Front-panel outputs (adjustable)

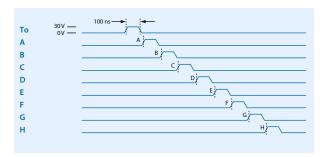
**Option 1** rear-panel outputs provide  $T_0$  and eight delay outputs (A, B, C, D, E, F, G and H) to allow the DG645 to be used as an 8-channel delay generator. The outputs go from 0 to 5 V at their programmed delays, and return low 25 ns after the longest delay.



Opt. 1 rear-panel outputs (5 V)

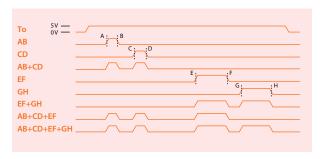


**Option 2** rear-panel outputs provide 30 V, 100 ns timing pulses at  $T_0$ , A, B, C, D, E, F, G and H. Output amplitudes are reduced to 15 V when driving 50  $\Omega$  loads.



Opt. 2 rear-panel outputs (30 V)

**Option 3** rear-panel outputs provide outputs  $T_0$ , AB, CD, EF, GH (with the same definition as the front-panel outputs), and (AB+CD), (EF+GH), (AB+CD+EF), (AB+CD+EF+GH) which provide two, three, or four pulses per trigger.



Opt. 3 rear-panel combinatorial outputs (5 V)



DG645 rear panel with option 1 outputs



**Delays** 

Channels 4 independent pulses controlled

in position and width. 8 delay channels available as an option

(see Output Options).

0 to 2000 s Range

Resolution 5 ps

Accuracy  $1 \text{ ns} + (\text{timebase error} \times \text{delay})$ 

Jitter (rms)

Ext. trig. to any output  $<25 \text{ ps} + (\text{timebase jitter} \times \text{delay})$  $<15 \text{ ps} + (\text{timebase jitter} \times \text{delay})$  $T_0$  to any output Trigger delay 85 ns (ext. trig. to  $T_0$  output)

**Timebases** 

Model # Type **Stability Jitter Aging** (s/s)(20 to 30 °C) (ppm/yr)  $10^{-8}$ Std.  $2 \times 10^{-6}$ 5 crystal Opt. 4 OCXO  $10^{-11}$  $1 \times 10^{-9}$ 0.2 Opt. 5 Rb  $10^{-11}$  $1 \times 10^{-10}$ 0.0005

External input  $10 \text{ MHz} \pm 10 \text{ ppm}$ , sine > 0.5 Vpp,

1 kΩ impedance

Output 10 MHz, 2 Vpp sine into 50  $\Omega$ 

**External Trigger** 

DC to 1/(100 ns + longest delay)Rate

(maximum of 10 MHz)

Threshold ±3.50 VDC

Slope Trigger on rising or falling edge

Impedance  $1 \text{ M}\Omega + 15 \text{ pF}$ 

**Internal Rate Generator** 

Continuous, line or single shot Trigger modes

Rate 100 µHz to 10 MHz

1 µHz Resolution

Accuracy Same as timebase

Jitter (rms) <25 ps (10 MHz/N trigger rate)

<100 ps (other trigger rates)

**Burst Generator** 

Trigger to first T<sub>0</sub>

Range 0 to 2000 s Resolution 5 ps

Period between pulses

100 ns to 42.9 s Range Resolution 10 ns

Delay cycles per burst  $1 \text{ to } 2^{32} - 1$ 

Outputs (T<sub>0</sub>, AB, CD, EF, and GH)

Source impedance 50 Ω Transition time <2 ns

Overshoot <100 mV + 10 % of pulse amplitude

Offset +2.V

Amplitude 0.5 to 5.0 V (level + offset < 6.0 V)100 mV + 5 % of pulse amplitude Accuracy

General

GPIB (IEEE-488.2), RS-232, and Computer interfaces

Ethernet. All instrument functions can be controlled through the interfaces.

Non-volatile memory Nine sets of instrument configurations

can be stored and recalled.

Power <100 W, 90 to 264 VAC, 47 Hz to 63 Hz

Dimensions  $8.5 \times 3.5 \times 13$  (WHD)

Weight

One year parts and labor on defects Warranty

in materials & workmanship

**Output Options** 

**Option 1 (8 Delay Outputs on Rear Panel)** 

T<sub>0</sub>, A, B, C, D, E, F, G and H Outputs (BNC)

5Ö Ω Source impedance Transition time <1 ns <100 mV Overshoot +5 V CMOS logic Level

Pulse characteristics

Rising edge At programmed delay Falling edge 25 ns after longest delay

**Option 2 (8 High-Voltage Delay Outputs on Rear Panel)** 

T<sub>0</sub>, A, B, C, D, E, F, G and H Outputs (BNC)

Source impedance  $50 \Omega$ Transition time <5 ns

Levels 0 to 30 V into high impedance

0 to 15 V into 50  $\Omega$ 

(amplitude decreases by 1 %/kHz)

Pulse Characteristics

Rising Edge At programmed delay Falling Edge 100 ns after the rising edge

**Option 3 (Combinatorial Outputs on Rear Panel)** 

 $T_0$ , AB, CD, EF, GH, (AB + CD), Outputs (BNC)

(EF + GH), (AB + CD + EF),

(AB + CD + EF + GH)

Source impedance  $50 \Omega$ Transition time <1 ns

<100 mV + 10 % of pulse amplitude Overshoot

Pulse characteristics

T<sub>0</sub>, AB, CD, EF, GH Logic high for time between delays (AB+CD), (EF+GH) Two pulses created by the logic OR

of the given channels

(AB+CD+EF) Three pulses created by the logic OR

of the given channels

(AB+CD+EF+GH) Four pulses created by the logic OR

of the given channels

**Option SRD1 (Fast Rise Time Module)** 

Rise time <100 ps Fall time <3 ns

0.8 V to 1.1 V Offset 0.5 V to 5.0 V Amplitude

 $50 \Omega$ Load